NSN 5961-01-132-5711

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-132-5711 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.080 inches **Overall Width:** 0.150 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -40.0 forward voltage, dc all transistor **Current Rating Per Characteristic:** 1.50 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0